National Semiconductor

February 1988

CD4071BM/CD4071BC
Quad 2-Input OR Buffered B Series Gate
CD4081BM/CD4081BC
Quad 2-Input AND Buffered B Series Gate

CD4071BM/CD4071BC Quad 2-Input OR Buffered B Series Gate
CD4081BM/CD4081BC Quad 2-Input AND Buffered B Series Gate

General Description

These quad gates are monolithic complementary MOS (CMOS) integrated circuits constructed with N- and P-channel enhancement mode transistors. They have equal source and sink current capabilities and conform to standard B series output drive. The devices also have buffered outputs which improve transfer characteristics by providing very high gain.

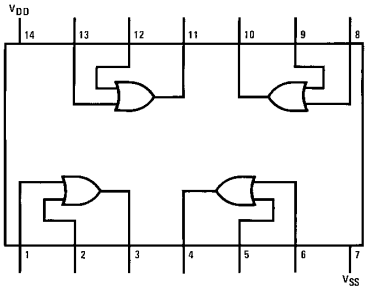
All inputs protected against static discharge with diodes to V_{DD} and V_{SS}.

Features

- Low power TTL compatibility — Fan out of 2 driving 74L or 1 driving 74LS
- 5V–10V–15V parametric ratings
- Symmetrical output characteristics
- Maximum input leakage 1 μA at 15V over full temperature range

Connection Diagrams

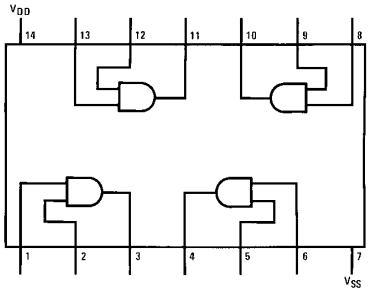
CD4071B Dual-In-Line Package



TL/F/5977–3

Top View

CD4081B Dual-In-Line Package



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Top View

Order Number CD4071B or CD4081B

RRD-B30M105/Printed in U. S. A.

Absolute Maximum Ratings (Notes 1 & 2)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Voltage at Any Pin	$-0.5V$ to $V_{DD} + 0.5V$
Power Dissipation (P_D)	
Dual-In-Line	700 mW
Small Outline	500 mW
V_{DD} Range	$-0.5\ V_{DC}$ to $+18\ V_{DC}$
Storage Temperature (T_S)	$-65°C$ to $+150°C$
Lead Temperature (T_L) (Soldering, 10 seconds)	260°C

Operating Conditions

Operating Range (V_{DD})	$3\ V_{DC}$ to $15\ V_{DC}$
Operating Temperature Range (T_A)	
CD4071BM, CD4081BM	$-55°C$ to $+125°C$
CD4071BC, CD4081BC	$-40°C$ to $+85°C$

DC Electrical Characteristics CD4071BM/CD4081BM (Note 2)

Symbol	Parameter	Conditions	$-55°C$		$+25°C$			$+125°C$		Units
			Min	Max	Min	Typ	Max	Min	Max	
I_{DD}	Quiescent Device Current	$V_{DD} = 5V$		0.25		0.004	0.25		7.5	μA
		$V_{DD} = 10V$		0.50		0.005	0.50		15	μA
		$V_{DD} = 15V$		1.0		0.006	1.0		30	μA
V_{OL}	Low Level Output Voltage	$V_{DD} = 5V$ | $\lvert I_O \rvert < 1\ \mu A$		0.05		0	0.05		0.05	V
		$V_{DD} = 10V$ | $\lvert I_O \rvert < 1\ \mu A$		0.05		0	0.05		0.05	V
		$V_{DD} = 15V$ | $\lvert I_O \rvert < 1\ \mu A$		0.05		0	0.05		0.05	V
V_{OH}	High Level Output Voltage	$V_{DD} = 5V$ | $\lvert I_O \rvert < 1\ \mu A$	4.95		4.95	5		4.95		V
		$V_{DD} = 10V$ | $\lvert I_O \rvert < 1\ \mu A$	9.95		9.95	10		9.95		V
		$V_{DD} = 15V$ | $\lvert I_O \rvert < 1\ \mu A$	14.95		14.95	15		14.95		V
V_{IL}	Low Level Input Voltage	$V_{DD} = 5V, V_O = 0.5V$		1.5		2	1.5		1.5	V
		$V_{DD} = 10V, V_O = 1.0V$		3.0		4	3.0		3.0	V
		$V_{DD} = 15V, V_O = 1.5V$		4.0		6	4.0		4.0	V
V_{IH}	High Level Input Voltage	$V_{DD} = 5V, V_O = 4.5V$	3.5		3.5	3		3.5		V
		$V_{DD} = 10V, V_O = 9.0V$	7.0		7.0	6		7.0		V
		$V_{DD} = 15V, V_O = 13.5V$	11.0		11.0	9		11.0		V
I_{OL}	Low Level Output Current (Note 3)	$V_{DD} = 5V, V_O = 0.4V$	0.64		0.51	0.88		0.36		mA
		$V_{DD} = 10V, V_O = 0.5V$	1.6		1.3	2.25		0.9		mA
		$V_{DD} = 15V, V_O = 1.5V$	4.2		3.4	8.8		2.4		mA
I_{OH}	High Level Output Current (Note 3)	$V_{DD} = 5V, V_O = 4.6V$	-0.64		-0.51	-0.88		-0.36		mA
		$V_{DD} = 10V, V_O = 9.5V$	-1.6		-1.3	-2.25		-0.9		mA
		$V_{DD} = 15V, V_O = 13.5V$	-4.2		-3.4	-8.8		-2.4		mA
I_{IN}	Input Current	$V_{DD} = 15V, V_{IN} = 0V$		-0.10		-10^{-5}	-0.10		-1.0	μA
		$V_{DD} = 15V, V_{IN} = 15V$		0.10		10^{-5}	0.10		1.0	μA

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.

Note 2: All voltages measured with respect to V_{SS} unless otherwise specified.

Note 3: I_{OH} and I_{OL} are tested one output at a time.

DC Electrical Characteristics CD4071BC/CD4081BC (Note 2)

Symbol	Parameter	Conditions	−40°C		+25°C			+85°C		Units
			Min	Max	Min	Typ	Max	Min	Max	
I_{DD}	Quiescent Device Current	V_{DD} = 5V		1		0.004	1		7.5	μA
		V_{DD} = 10V		2		0.005	2		15	μA
		V_{DD} = 15V		4		0.006	4		30	μA
V_{OL}	Low Level Output Voltage	V_{DD} = 5V, $\|I_O\| < 1$ μA		0.05		0	0.05		0.05	V
		V_{DD} = 10V, $\|I_O\| < 1$ μA		0.05		0	0.05		0.05	V
		V_{DD} = 15V, $\|I_O\| < 1$ μA		0.05		0	0.05		0.05	V
V_{OH}	High Level Output Voltage	V_{DD} = 5V, $\|I_O\| < 1$ μA	4.95		4.95	5		4.95		V
		V_{DD} = 10V, $\|I_O\| < 1$ μA	9.95		9.95	10		9.95		V
		V_{DD} = 15V, $\|I_O\| < 1$ μA	14.95		14.95	15		14.95		V
V_{IL}	Low Level Input Voltage	V_{DD} = 5V, V_O = 0.5V		1.5		2	1.5		1.5	V
		V_{DD} = 10V, V_O = 1.0V		3.0		4	3.0		3.0	V
		V_{DD} = 15V, V_O = 1.5V		4.0		6	4.0		4.0	V
V_{IH}	High Level Input Voltage	V_{DD} = 5V, V_O = 4.5V	3.5		3.5	3		3.5		V
		V_{DD} = 10V, V_O = 9.0V	7.0		7.0	6		7.0		V
		V_{DD} = 15V, V_O = 13.5V	11.0		11.0	9		11.0		V
I_{OL}	Low Level Output Current (Note 3)	V_{DD} = 5V, V_O = 0.4V	0.52		0.44	0.88		0.36		mA
		V_{DD} = 10V, V_O = 0.5V	1.3		1.1	2.25		0.9		mA
		V_{DD} = 15V, V_O = 1.5V	3.6		3.0	8.8		2.4		mA
I_{OH}	High Level Output Current (Note 3)	V_{DD} = 5V, V_O = 4.6V	−0.52		−0.44	−0.88		−0.36		mA
		V_{DD} = 10V, V_O = 9.5V	−1.3		−1.1	−2.25		−0.9		mA
		V_{DD} = 15V, V_O = 13.5V	−3.6		−3.0	−8.8		−2.4		mA
I_{IN}	Input Current	V_{DD} = 15V, V_{IN} = 0V		−0.30		-10^{-5}	−0.30		−1.0	μA
		V_{DD} = 15V, V_{IN} = 15V		0.30		10^{-5}	0.30		1.0	μA

AC Electrical Characteristics* CD4071BC/CD4071BM

T_A = 25°C, Input t_r; t_f = 20 ns, C_L = 50 pF, R_L = 200 kΩ, Typical temperature coefficient is 0.3%/°C

Symbol	Parameter	Conditions	Typ	Max	Units
t_{PHL}	Propagation Delay Time, High-to-Low Level	V_{DD} = 5V	100	250	ns
		V_{DD} = 10V	40	100	ns
		V_{DD} = 15V	30	70	ns
t_{PLH}	Propagation Delay Time, Low-to-High Level	V_{DD} = 5V	90	250	ns
		V_{DD} = 10V	40	100	ns
		V_{DD} = 15V	30	70	ns
t_{THL}, t_{TLH}	Transition Time	V_{DD} = 5V	90	200	ns
		V_{DD} = 10V	50	100	ns
		V_{DD} = 15V	40	80	ns
C_{IN}	Average Input Capacitance	Any Input	5	7.5	pF
C_{PD}	Power Dissipation Capacity	Any Gate	18		pF

*AC Parameters are guaranteed by DC correlated testing.

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.

Note 2: All voltages measured with respect to V_{SS} unless otherwise specified.

Note 3: I_{OH} and I_{OL} are tested one output at a time.

AC Electrical Characteristics* CD4081BC/CD4081BM

T_A = 25°C, Input t_r; t_f = 20 ns, C_L = 50 pF, R_L = 200 kΩ, Typical temperature coefficient is 0.3%/°C

Symbol	Parameter	Conditions	Typ	Max	Units
t_{PHL}	Propagation Delay Time, High-to-Low Level	V_{DD} = 5V	100	250	ns
		V_{DD} = 10V	40	100	ns
		V_{DD} = 15V	30	70	ns
t_{PLH}	Propagation Delay Time, Low-to-High Level	V_{DD} = 5V	120	250	ns
		V_{DD} = 10V	50	100	ns
		V_{DD} = 15V	35	70	ns
t_{THL}, t_{TLH}	Transition Time	V_{DD} = 5V	90	200	ns
		V_{DD} = 10V	50	100	ns
		V_{DD} = 15V	40	80	ns
C_{IN}	Average Input Capacitance	Any Input	5	7.5	pF
C_{PD}	Power Dissipation Capacity	Any Gate	18		pF

*AC Parameters are guaranteed by DC correlated testing.

Typical Performance Characteristics

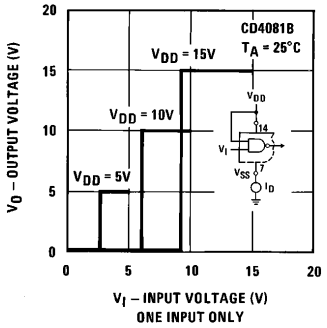

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FIGURE 1. Typical Transfer Characteristics

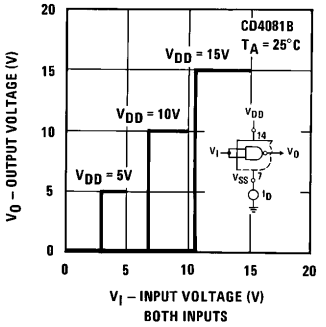

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FIGURE 2. Typical Transfer Characteristics

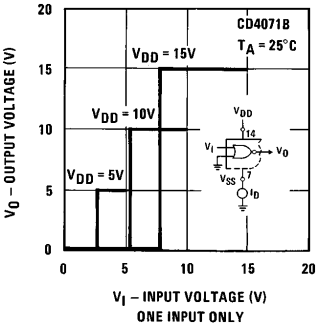

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FIGURE 3. Typical Transfer Characteristics

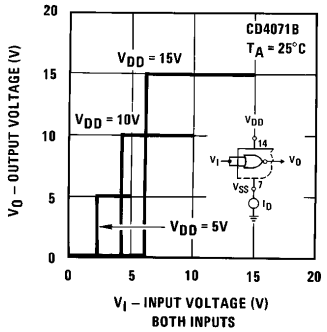

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FIGURE 4. Typical Transfer Characteristics

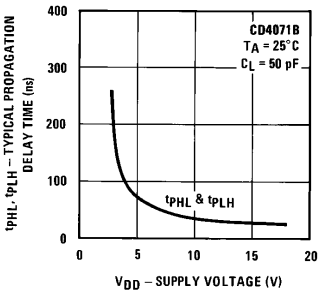

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FIGURE 5

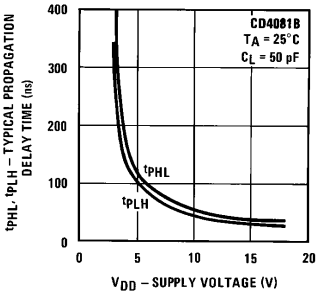

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FIGURE 6

Typical Performance Characteristics (Continued)

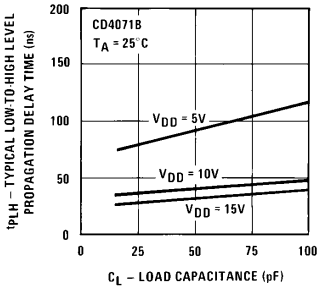

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FIGURE 7

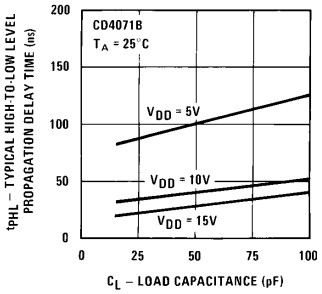

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FIGURE 8

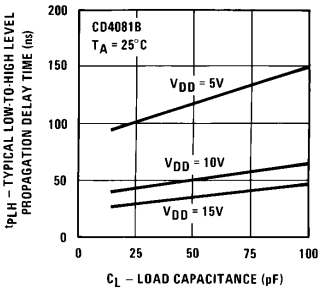

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FIGURE 9

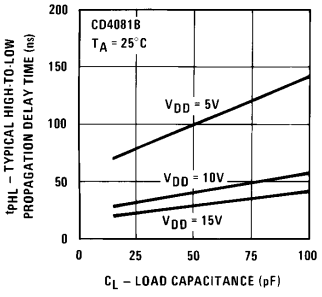

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FIGURE 10

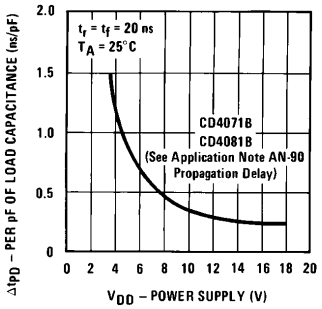

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FIGURE 11

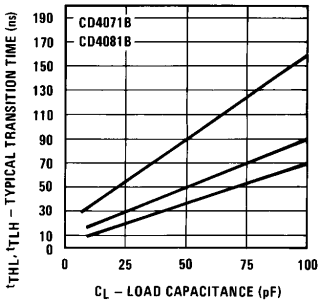

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FIGURE 12

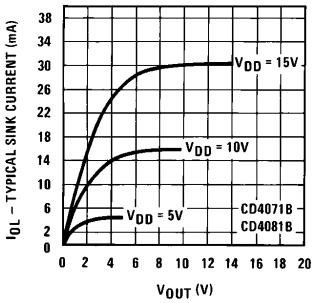

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FIGURE 13

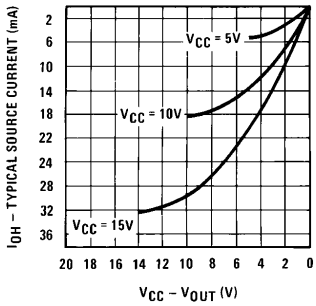

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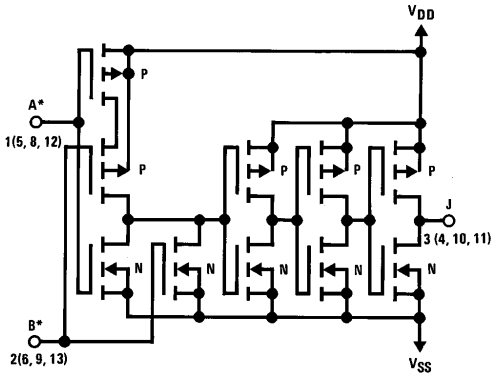
FIGURE 14

Schematic Diagrams

CD4071B



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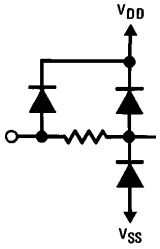

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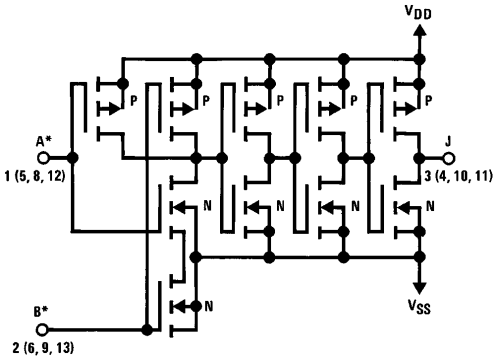
¼ of device shown

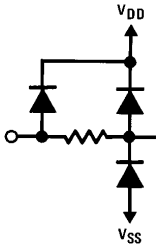
J = A + B
Logical "1" = High
Logical "0" = Low

*All inputs protected by standard CMOS protection circuit.

CD4081B



TL/F/5977–4



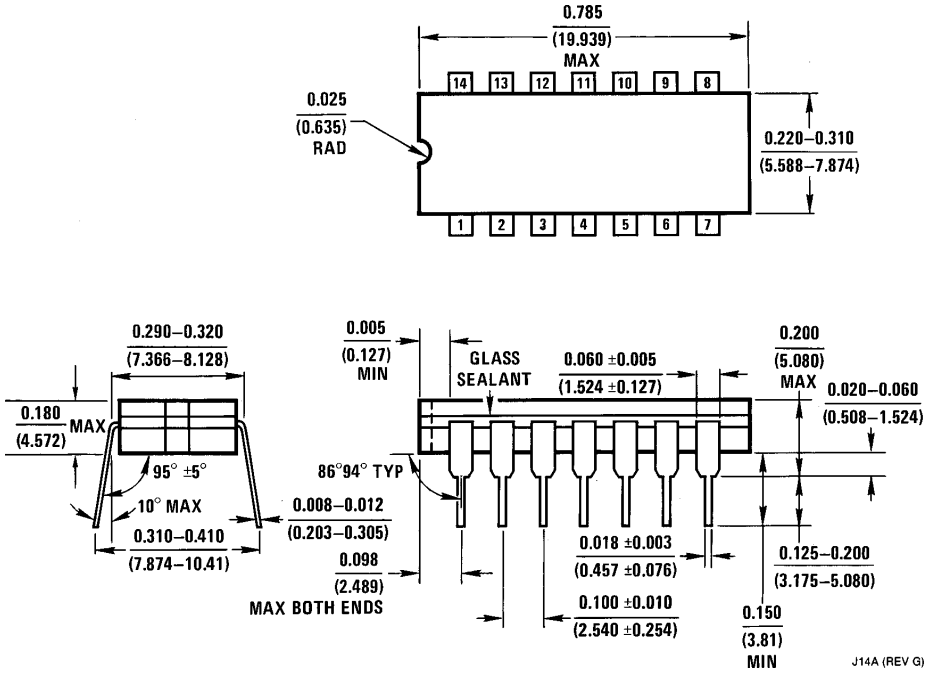
TL/F/5977–5

¼ of device shown

J = A • B
Logical "1" = High
Logical "0" = Low

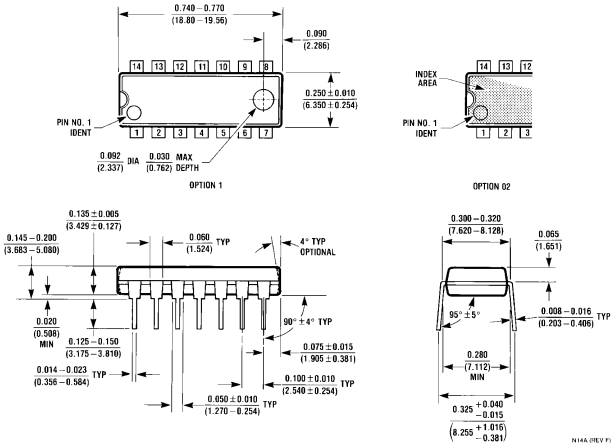
*All inputs protected by standard CMOS protection circuit.

Physical Dimensions inches (millimeters)



Ceramic Dual-In-Line Package (J)
Order Number CD4071BMJ, CD4071BCJ
CD4081BMJ or CD4081BCJ
NS Package Number J14A

Physical Dimensions inches (millimeters) (Continued)



Molded Dual-In-Line Package (N)
Order Number CD4071BMN, CD4071BCN
CD4081BMN or CD4081BCN
NS Package Number N14A

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2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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